



Flash Memory Summit to Present Lifetime Achievement Award to Dr. Simon Min Sze

Floating-gate transistor co-inventor to be honored August 7th for his influence on the non-volatile semiconductor memory device field

SANTA CLARA, CA – July 2nd, 2014 – Flash Memory Summit (“FMS”) is pleased to announce that it will present the 2014 Lifetime Achievement Award to Dr. Simon Min Sze. Dr. Sze is the co-inventor of floating gate non-volatile semiconductor memory and provided the basis for today’s non-volatile flash devices. His invention has led to such hugely popular consumer electronics as smartphones, GPS devices, ultrabooks, and tablets. Dr. Sze has also made significant technical contributions in other areas such as metal-semiconductor contacts, microwave devices, and submicron MOSFET technology. He has written over 200 technical papers and has written or edited 16 books. He is currently a National Endowed Chair Professor of Electrical Engineering at National Chiao Tung University (Taiwan). He is also an academican of the Academia Sinica, a foreign member of the Chinese Academy of Engineering, and a member of the US National Academy of Engineering.

Flash Memory Summit has previously given the Lifetime Achievement Award to flash memory inventor Dr. Fujio Masuoka in 2013, Eli Harari, SanDisk founder and NVM technology expert, in 2012, and Intel’s Flash Memory team in 2011. This year’s award will be presented at 11 am on Thursday, August 7 at the Santa Clara Convention Center. [Admission](#) is free to all who would like to attend the ceremony.

About the Flash Memory Summit

Flash Memory Summit (FMS), produced by Conference ConConcepts, showcases the mainstream applications, key technologies, and leading vendors that are driving the multi-billion dollar non-volatile memory and SSD markets. FMS is now the world’s largest event featuring the trends, innovations, and influencers driving the adoption of Flash memory in enterprise storage applications, as well as in smartphones, tablets, and embedded systems. The 2014 event takes place on August 5-7 at the Santa Clara Convention Center in Santa Clara, California.



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